DATASHEET

## **General Description**

The 9ZX21901 is Intel DB1900Z Differential Buffer suitable for PCI-Express Gen3 or QPI applications. The part is backwards compatible to PCIe Gen1 and Gen2. A fixed external feedback maintains low drift for critical QPI applications. In bypass mode, the 9ZX21901 can provide outputs up to 400MHz.

## **Recommended Application**

• 19-output PCIe Gen3/QPI buffer with fixed feedback for Romley platforms

### **Output Features**

• 19 – 0.7V current mode differential HCSL output pairs

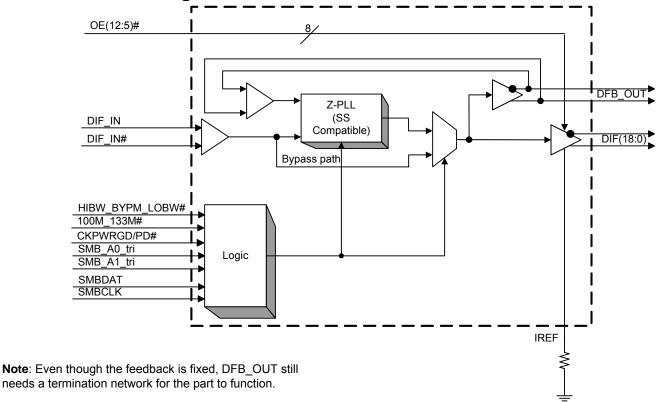
## **Key Specifications**

- Cycle-to-cycle jitter: < 50ps
- Output-to-output skew: <65ps</li>
- Input-to-output delay: Fixed at 0 ps
- Input-to-output delay variation: <50ps</li>
- Phase jitter: PCle Gen3 < 1ps rms</li>
- Phase jitter: QPI 9.6GB/s < 0.2ps rms

#### Features/Benefits

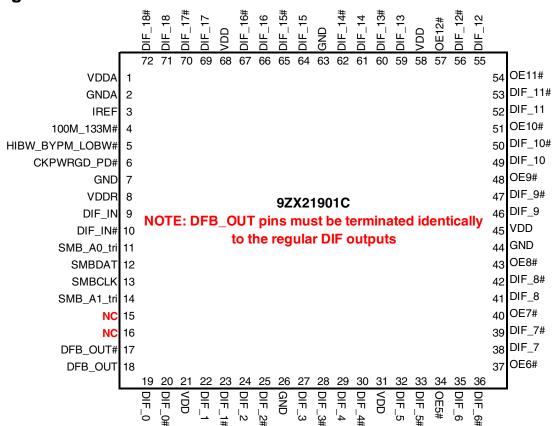
- Fixed feedback path/ 0ps input-to-output delay
- 9 Selectable SMBus addresses; Multiple devices can share same SMBus segment
- 8 dedicated OE# pins; hardware control of outputs
- PLL or bypass mode; PLL can dejitter incoming clock
- Selectable PLL BW; minimizes jitter peaking in downstream PLL's
- Spread spectrum compatible; tracks spreading input clock for EMI reduction
- SMBus Interface; unused outputs can be disabled
- 100MHz & 133.33MHz PLL mode; legacy QPI support
- Undriven differential outputs in Power Down mode for maximum power savings

**Functional Block Diagram** 





## **Pin Configuration**



72-pin VFQFPN

Functionality at Power Up (PLL Mode)

r directionality at 1 ower	op (i EE Mode)			
100M_133M#	DIF_IN (MHz)	DIF_x (MHz)		
1	100.00	DIF_IN		
0	133.33	DIF_IN		

**PLL Operating Mode Readback Table** 

HiBW_BypM_LoBW#	Byte0, bit 7	Byte 0, bit 6					
Low (Low BW)	0	0					
Mid (Bypass)	0	1					
High (High BW)	1	1					

**PLL Operating Mode** 

HiBW_BypM_LoBW#	MODE
Low	PLL Lo BW
Mid	Bypass
High	PLL Hi BW

NOTE: PLL is OFF in Bypass Mode

Tri-level Input Thresholds

Tri-level input Thresholds					
Level	Voltage				
Low	<0.8V				
Mid	1.2 <vin<1.8v< td=""></vin<1.8v<>				
High	Vin > 2.2V				

#### **Power Connections**

Pin Nu		
VDD	GND	Description
1	2	Analog PLL
8	7	Analog Input
21, 31, 45, 58, 68	26, 44, 63	DIF clocks

9ZX21901 SMBus Addressing

Pi	n	SMBus Address
SMB_A1_tri	SMB_A0_tri	(Rd/Wrt bit = 0)
0	0	D8
0	М	DA
0	1	DE
М	0	C2
M	М	C4
М	1	C6
1	0	CA
1	M	CC
1	1	CE



# **Pin Descriptions**

PIN#	PIN NAME	PIN TYPE	DESCRIPTION
1	VDDA	PWR	3.3V power for the PLL core.
2	GNDA	GND	Ground pin for the PLL core.
3	IREF	OUT	This pin establishes the reference for the differential current-mode output pairs. It requires a fixed precision resistor to ground. 4750hm is the standard value for 1000hm differential impedance. Other impedances require different values. See data sheet.
4	100M_133M#	IN	Input to select operating frequency 1 = 100MHz, 0 = 133.33MHz
5	HIBW_BYPM_LOBW#	IN	Trilevel input to select High BW, Bypass or Low BW mode. See PLL Operating Mode Table for Details.
6	CKPWRGD_PD#	IN	3.3V Input notifies device to sample latched inputs and start up on first high assertion, or exit Power Down Mode on subsequent assertions. Low enters Power Down Mode.
7	GND	GND	Ground pin.
8	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately.
9	DIF_IN	IN	0.7 V Differential True input
10	DIF_IN#	IN	0.7 V Differential Complementary Input
11	SMB_A0_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A1 to decode 1 of 9 SMBus Addresses.
12	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
13	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
14	SMB_A1_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A0 to decode 1 of 9 SMBus Addresses.
15	NC	N/A	No Connection.
16	NC	N/A	No Connection.
17	DFB_OUT#	OUT	Complementary half of differential feedback output, provides feedback signal to the PLL for synchronization with input clock to eliminate phase error.
18	DFB_OUT	OUT	True half of differential feedback output, provides feedback signal to the PLL for synchronization with the input clock to eliminate phase error.
19	DIF_0	OUT	0.7V differential true clock output
20	 DIF_0#	OUT	0.7V differential Complementary clock output
21	VDD	PWR	Power supply, nominal 3.3V
22	DIF_1	OUT	0.7V differential true clock output
23	DIF_1#	OUT	0.7V differential Complementary clock output
24	DIF_2	OUT	0.7V differential true clock output
25	DIF_2#	OUT	0.7V differential Complementary clock output
26	GND	GND	Ground pin.
27	DIF_3	OUT	0.7V differential true clock output
28	DIF_3#	OUT	0.7V differential Complementary clock output
29	DIF_4	OUT	0.7V differential true clock output
30	DIF_4#	OUT	0.7V differential Complementary clock output
31	VDD	PWR	Power supply, nominal 3.3V
32	DIF_5	OUT	0.7V differential true clock output
33	DIF_5#	OUT	0.7V differential Complementary clock output
34	OE5#	IN	Active low input for enabling DIF pair 5.  1 =disable outputs, 0 = enable outputs
35	DIF_6	OUT	0.7V differential true clock output
36	DIF_6#	OUT	0.7V differential Complementary clock output



# Pin Descriptions (cont.)

37 38 39 40 41 42	PIN NAME  OE6#  DIF_7  DIF_7#	IN	Active low input for enabling DIF pair 6.  1 =disable outputs, 0 = enable outputs
38 39 40 41	DIF_7		•
39 40 41			I =disable outbus. U = enable outbus
40 41		OUT	0.7V differential true clock output
40 41		OUT	0.7V differential Complementary clock output
41	057"	INI	Active low input for enabling DIF pair 7.
	OE7#	IN	1 =disable outputs, 0 = enable outputs
40	DIF_8	OUT	0.7V differential true clock output
42	DIF_8#	OUT	0.7V differential Complementary clock output
43	OE8#	IN	Active low input for enabling DIF pair 8.
43	OL0#	IIN	1 =disable outputs, 0 = enable outputs
44	GND	GND	Ground pin.
45	VDD	PWR	Power supply, nominal 3.3V
46	DIF_9	OUT	0.7V differential true clock output
47	DIF_9#	OUT	0.7V differential Complementary clock output
48	OE9#	IN	Active low input for enabling DIF pair 9.
40			1 =disable outputs, 0 = enable outputs
49	DIF_10	OUT	0.7V differential true clock output
50	DIF_10#	OUT	0.7V differential Complementary clock output
51	OE10#	IN	Active low input for enabling DIF pair 10.
			1 =disable outputs, 0 = enable outputs
52	DIF_11	OUT	0.7V differential true clock output
53	DIF_11#	OUT	0.7V differential Complementary clock output
54	OE11#	IN	Active low input for enabling DIF pair 11.
			1 =disable outputs, 0 = enable outputs
55	DIF_12	OUT	0.7V differential true clock output
56	DIF_12#	OUT	0.7V differential Complementary clock output
57	OE12#	IN	Active low input for enabling DIF pair 12.
50	VDD	DWD	1 =disable outputs, 0 = enable outputs
58	VDD	PWR	Power supply, nominal 3.3V
59	DIF_13	OUT	0.7V differential true clock output
60	DIF_13#	OUT	0.7V differential Complementary clock output
61 62	DIF_14 DIF_14#	OUT	0.7V differential true clock output
63	GND	GND	0.7V differential Complementary clock output
64	DIF_15	OUT	Ground pin. 0.7V differential true clock output
65	DIF_15#	OUT	0.7V differential true clock output  0.7V differential Complementary clock output
66	DIF_16	OUT	0.7V differential complementary clock output
67	DIF_16#	OUT	0.7V differential Complementary clock output
68	VDD	PWR	Power supply, nominal 3.3V
69	DIF_17	OUT	0.7V differential true clock output
70	DIF_17#	OUT	0.7V differential Complementary clock output
71	DIF_18	OUT	0.7V differential true clock output
72	DIF_18#	OUT	0.7V differential Complementary clock output



# **Electrical Characteristics – Absolute Maximum Ratings**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
3.3V Core Supply Voltage	VDDA				4.6	V	1,2
3.3V Logic Supply Voltage	VDD				4.6	<b>V</b>	1,2
Input Low Voltage	$V_{IL}$		GND-0.5			٧	1
Input High Voltage	$V_{IH}$	Except for SMBus interface			V <sub>DD</sub> +0.5V	V	1
Input High Voltage	$V_{IHSMB}$	SMBus clock and data pins			5.5V	٧	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Case Temperature	Tc				110	°C	1
Input ESD protection	ESD prot	Human Body Model	2000	•		V	1

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

## **Electrical Characteristics – DIF\_IN Clock Input Parameters**

T<sub>AMB</sub>=T<sub>COM</sub> unless otherwise indicated, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

		11 7 0 1					
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V <sub>CROSS</sub>	Cross Over Voltage	150		900	mV	1
Input Swing - DIF_IN	$V_{SWING}$	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{DD}$ , $V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d <sub>tin</sub>	Measurement from differential wavefrom	45		55	%	1
Input Jitter - Cycle to Cycle	$J_{DIFIn}$	Differential Measurement	0		125	ps	1

<sup>&</sup>lt;sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

## **Electrical Characteristics – Current Consumption**

 $TA = T_{COM}$ ; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I <sub>DD3.3OP</sub>	All outputs active @100MHz, C <sub>L</sub> = Full load;		407	500	mA	1
Powerdown Current	I <sub>DD3.3PDZ</sub>	All differential pairs tri-stated		12	36	mA	1

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> Operation under these conditions is neither implied nor guaranteed.

<sup>&</sup>lt;sup>2</sup>Slew rate measured through +/-75mV window centered around differential zero



# **Electrical Characteristics – Input/Supply/Common Parameters**

 $TA = T_{COM}$ ; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

COM, 117							
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Ambient Operating Temperature	T <sub>COM</sub>	Commmercial range	0		70	°C	1
Input High Voltage	V <sub>IH</sub>	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V <sub>DD</sub> + 0.3	٧	1
Input Low Voltage	$V_{IL}$	Single-ended inputs, except SMBus, low threshold and tri-level inputs	GND - 0.3		0.8	<b>V</b>	1
	I <sub>IN</sub>	Single-ended inputs, $V_{IN} = GND$ , $V_{IN} = VDD$	<b>-</b> 5		5	uA	1
Input Current	I <sub>INP</sub>	$\label{eq:VIN} Single-ended inputs \\ V_{IN} = 0 \ V; \ Inputs \ with internal \ pull-up \ resistors \\ V_{IN} = VDD; \ Inputs \ with \ internal \ pull-down \ resistors$	-200		200	uA	1
	$F_{ibyp}$	V <sub>DD</sub> = 3.3 V, Bypass mode	33		400	MHz	2
Input Frequency	$F_{ipll}$	$V_{DD} = 3.3 \text{ V}, 100\text{MHz PLL mode}$	90	100.00	105	MHz	2
	$F_{ipll}$	$V_{DD} = 3.3 \text{ V}, 133.33 \text{MHz PLL mode}$	120	133.33	140	MHz	2
Pin Inductance	$L_{pin}$				7	nΗ	1
	C <sub>IN</sub>	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C <sub>INDIF_IN</sub>	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
·	C <sub>OUT</sub>	Output pin capacitance			6	pF	1
Clk Stabilization	T <sub>STAB</sub>	From V <sub>DD</sub> Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1.8	ms	1,2
Input SS Modulation Frequency	f <sub>MODIN</sub>	Allowable Frequency (Triangular Modulation)	30		33	kHz	1
OE# Latency	t <sub>LATOE#</sub>	DIF start after OE# assertion DIF stop after OE# deassertion	4		12	clocks	1,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t <sub>F</sub>	Fall time of control inputs			5	ns	1,2
Trise	t <sub>R</sub>	Rise time of control inputs			5	ns	1,2
SMBus Input Low Voltage	$V_{ILSMB}$				0.8	V	1
SMBus Input High Voltage	$V_{IHSMB}$		2.1		$V_{DDSMB}$	V	1
SMBus Output Low Voltage	$V_{OLSMB}$	@ I <sub>PULLUP</sub>			0.4	V	1
SMBus Sink Current	I <sub>PULLUP</sub>	@ V <sub>OL</sub>	4			mA	1
Nominal Bus Voltage	$V_{\text{DDSMB}}$	3V to 5V +/- 10%	2.7		5.5	V	1
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			100	kHz	1,5

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup>Control input must be monotonic from 20% to 80% of input swing.

<sup>&</sup>lt;sup>3</sup>Time from deassertion until outputs are >200 mV

<sup>&</sup>lt;sup>4</sup> DIF\_IN input

<sup>&</sup>lt;sup>5</sup>The differential input clock must be running for the SMBus to be active



## **Electrical Characteristics – DIF 0.7V Current Mode Differential Outputs**

TA = T<sub>COM</sub>: Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on	1	2.5	4	V/ns	1, 2, 3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on			20	%	1, 2, 4
Rise/Fall Time Matching	ΔTrf	Rise/fall matching, Scope averaging off			125	ps	1, 7, 8
Voltage High	VHigh	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	660	750	850	mV	1
Voltage Low	VLow	averaging on)	-150		150	] ""	1
Max Voltage	Vmax	Measurement on single ended signal using			1150	mV	1
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300			IIIV	1
Vswing	Vswing	Scope averaging off	300			mV	1, 2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250		550	mV	1, 5
Crossing Voltage (var)	Δ-Vcross	Scope averaging off			140	mV	1, 6

 $<sup>^{1}</sup>$ Guaranteed by design and characterization, not 100% tested in production. IREF = VDD/(3xR<sub>R</sub>). For R<sub>R</sub> = 475Ω (1%), I<sub>REF</sub> = 2.32mA. I<sub>OH</sub> = 6 x I<sub>REF</sub> and V<sub>OH</sub> = 0.7V @ Z<sub>O</sub>=50Ω (100Ω differential impedance).

<sup>&</sup>lt;sup>2</sup> Measured from differential waveform

<sup>&</sup>lt;sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

<sup>&</sup>lt;sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>&</sup>lt;sup>5</sup> Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>&</sup>lt;sup>6</sup> The total variation of all Vcross measurements in any particular system. Note that this is a subset of V\_cross\_min/max (V\_cross absolute) allowed. The intent is to limit Vcross induced modulation by setting V\_cross\_delta to be smaller than V\_cross absolute.

<sup>&</sup>lt;sup>7</sup> Measured from single-ended waveform

<sup>&</sup>lt;sup>8</sup> Measured with scope averaging off, using statistics function. Variation is difference between min and max.



#### **Electrical Characteristics – Skew and Differential Jitter Parameters**

TA = T<sub>COM</sub>: Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
CLK_IN, DIF[x:0]	t <sub>SPO_PLL</sub>	Input-to-Output Skew in PLL mode nominal value @ 25°C, 3.3V	-100	0	100	ps	1,2,4,5,8
CLK_IN, DIF[x:0]	t <sub>PD_BYP</sub>	Input-to-Output Skew in Bypass mode nominal value @ 25°C, 3.3V	2.5	3.5	4.5	ns	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>DSPO_PLL</sub>	Input-to-Output Skew Varation in PLL mode across voltage and temperature	-50	0	50	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>DSPO_BYP</sub>	Input-to-Output Skew Varation in Bypass mode across voltage and temperature	-250		250	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>DTE</sub>	Random Differential Tracking error beween two 9ZX devices in Hi BW Mode		3	5	ps (rms)	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>DSSTE</sub>	Random Differential Spread Spectrum Tracking error beween two 9ZX devices in Hi BW Mode		15	75	ps	1,2,3,5,8
DIF{x:0]	t <sub>SKEW_ALL</sub>	Output-to-Output Skew across all outputs (Common to Bypass and PLL mode)		37	65	ps	1,2,3,8
PLL Jitter Peaking	<b>j</b> peak-hibw	LOBW#_BYPASS_HIBW = 1	0	1.3	2.5	dB	7,8
PLL Jitter Peaking	jpeak-lobw	LOBW#_BYPASS_HIBW = 0	0	0.8	2	dB	7,8
PLL Bandwidth	pll <sub>HIBW</sub>	LOBW#_BYPASS_HIBW = 1	2	3	4	MHz	8,9
PLL Bandwidth	pll <sub>LOBW</sub>	LOBW#_BYPASS_HIBW = 0	0.7	1.1	1.4	MHz	8,9
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	50	55	%	1
Duty Cycle Distortion	t <sub>DCD</sub>	Measured differentially, Bypass Mode @100MHz	-2	0	2	%	1,10
Jitter, Cycle to cycle	t.	PLL mode		41	50	ps	1,11
onter, Cycle to cycle	t <sub>jcyc-cyc</sub>	Additive Jitter in Bypass Mode		20	50	ps	1,11

#### Notes for preceding table:

<sup>&</sup>lt;sup>1</sup> Measured into fixed 2 pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

<sup>&</sup>lt;sup>2</sup> Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

<sup>&</sup>lt;sup>3</sup> All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

<sup>&</sup>lt;sup>4</sup> This parameter is deterministic for a given device

<sup>&</sup>lt;sup>5</sup> Measured with scope averaging on to find mean value. DIF\_IN slew rate must be matched to DIF output slew rate.

<sup>&</sup>lt;sup>6</sup>.t is the period of the input clock

<sup>&</sup>lt;sup>7</sup> Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

<sup>&</sup>lt;sup>8.</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>9</sup> Measured at 3 db down or half power point.

<sup>&</sup>lt;sup>10</sup> Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

<sup>&</sup>lt;sup>11</sup> Measured from differential waveform



## **Electrical Characteristics – Phase Jitter Parameters**

TA = T<sub>COM</sub>; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
	t <sub>jphPCleG1</sub>	PCIe Gen 1		39	86	ps (p-p)	1,2,3
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.1	3	ps (rms)	1,2
Jitter, Phase	t <sub>jphPCleG2</sub>	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.6	3.1	ps (rms)	1,2
	t <sub>jphPCleG3</sub>	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.6	1	ps (rms)	1,2,4
		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.36	0.5	ps (rms)	1,5
	t <sub>jphQPI_SMI</sub>	QPI & SMI (100MHz, 8.0Gb/s, 12UI)	0.23		0.3	ps (rms)	1,5
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.18	0.2	ps (rms)	1,5
	t <sub>iphPCleG1</sub>	PCIe Gen 1		4	10	ps (p-p)	1,2,3
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.25	0.3	ps (rms)	1,2,6
	t <sub>jphPCleG2</sub>	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.57	0.7	ps (rms)	1,2,6
Additive Phase Jitter, Bypass mode	t <sub>jphPCleG3</sub>	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.20	0.3	ps (rms)	1,2,4,6
Bypass mode		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.22	0.3	ps (rms)	1,5,6
	t <sub>jphQPI_SMI</sub>	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.08	0.1	ps (rms)	1,5,6
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.08	0.1	ps (rms)	1,5,6

<sup>&</sup>lt;sup>1</sup> Applies to all outputs.

**Power Management Table** 

Inputs		Control Bits/Pins					
CKPWRGD_PD#	DIF_IN/ DIF_IN#	SMBus EN bit			IF(5:12)/ Other DIF/ DFB_OUT/ IF(5:12)# DIF# DFB_OUT#		PLL State
0	Х	Х	Х	Hi-Z <sup>1</sup>	Hi-Z <sup>1</sup>	Hi-Z <sup>1</sup>	OFF
		0	Χ	Hi-Z <sup>1</sup>	Hi-Z <sup>1</sup>	Running	ON
1	Running	1	0	Running	Running	Running	ON
		1	1	Hi-Z <sup>1</sup>	Running	Running	ON

NOTE: 1. Due to external pull down resistors, HI-Z results in Low/Low on the True/Complement outputs

<sup>&</sup>lt;sup>2</sup> See http://www.pcisig.com for complete specs

<sup>&</sup>lt;sup>3</sup> Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

<sup>&</sup>lt;sup>4</sup> Subject to final radification by PCI SIG.

<sup>&</sup>lt;sup>5</sup> Calculated from Intel-supplied Clock Jitter Tool v 1.6.3

<sup>&</sup>lt;sup>6</sup> For RMS figures, additive jitter is calculated by solving the following equation: (Additive jitter)<sup>2</sup> = (total jitter)<sup>2</sup> - (input jitter)<sup>2</sup>



## Clock Periods - Differential Outputs with Spread Spectrum Disabled

			Measurement Window							
	0	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3
DIF	133.33	7.44925		7.49925	7.50000	7.50075		7.55075	ns	1,2,4

# Clock Periods - Differential Outputs with Spread Spectrum Enabled

			Measurement Window							
SSC ON	Center Freq. MHz	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
		-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3
DIF	133.00	7.44930	7.49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	1,2,4

#### Notes:

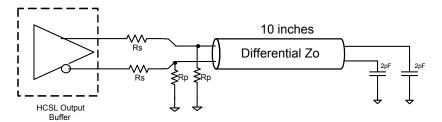
#### **Thermal Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to Ambient	θЈА	Still air		26.2		°C/W
	θЈА	1 m/s air flow		23.1		°C/W
	θЈА	3 m/s air flow		19.6		°C/W
Thermal Resistance Junction to Case	θЈС			10.4		°C/W
Thermal Resistance Junction to Board	θЈВ			0.3		°C/W

#### **Differential Output Termination Table**

DIF Zo (Ω)	Iref (Ω)	Rs $(\Omega)$	Rp (Ω)
100	475	33	50
85	412	27	42.2 or 43.2

#### 9ZX21901 Differential Test Loads



<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (+/-100ppm). The 96Z61027 itself does not contribute to ppm error.

<sup>&</sup>lt;sup>3</sup> Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

<sup>&</sup>lt;sup>4</sup> Driven by CPU output of main clock, 133 MHz PLL Mode or Bypass mode



# General SMBus Serial Interface Information (see also 9ZX21901 SMBus Addressing on page 2)

#### **How to Write**

- Controller (host) sends a start bit
- Controller (host) sends the write address XX<sub>(H)</sub>
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index BI	ock W	/rite Operation
Controll	er (Host)		IDT (Slave/Receiver)
T	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Data Byte Count = X		
			ACK
Beginnir	ng Byte N		
			ACK
0		$ \times $	
0		X Byte	0
0		O	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note:  $XX_{(H)}$  is defined by SMBus Address select pins.

#### How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address XX<sub>(H)</sub>
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address YY<sub>(H)</sub>
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	Read O	peration
Cor	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		ē	0
	0	X Byte	0
	0		0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		



SMBusTable: PLL Mode, and Frequency Select Register

Byte	0 Pin#	Name	Control Function	Type	0	1	Default
Bit 7	5	PLL Mode 1	PLL Operating Mode Rd back 1	R	See PLL Operating Mode		Latch
Bit 6	5	PLL Mode 0	PLL Operating Mode Rd back 0	R Readback Table		Latch	
Bit 5	72/71	DIF_18_En	Output Control overrides OE# pin	RW	Hi-Z	Enable	1
Bit 4	70/69	DIF_17_En	Output Control overrides OE# pin	RW	Hi-Z	Enable	1
Bit 3	67/66	DIF_16_En	Output Control overrides OE# pin	RW	Hi-Z	Enable	1
Bit 2			Reserved				0
Bit 1		Reserved					
Bit 0	4	100M 133M#	Frequency Select Readback	R	133MHz	100MHz	Latch

SMBusTable: Output Control Register

Byte	1 Pin #	Name	Control Function	Type	0	1	Default
Bit 7	39/38	DIF_7_En	Output Control overrides OE# pin	RW			1
Bit 6	35/36	DIF_6_En	Output Control overrides OE# pin	RW			1
Bit 5	32/33	DIF_5_En	Output Control overrides OE# pin	RW			1
Bit 4	29/30	DIF_4_En	Output Control overrides OE# pin	RW	Hi-Z	Enable	1
Bit 3	27/28	DIF_3_En	Output Control overrides OE# pin	RW	□ -∠		1
Bit 2	24/25	DIF_2_En	Output Control overrides OE# pin	RW			1
Bit 1	22/23	DIF_1_En	Output Control overrides OE# pin	RW	Ī		
Bit 0	19/20	DIF 0 Fn	Output Control overrides OF# pin	RW	1		1

SMBusTable: Output Control Register

Byte	Byte 2 Pin # Name		Control Function	Type	0	1	Default
Bit 7	65/64 DIF_15_En Output Control overrides OE# pin		Output Control overrides OE# pin	RW			1
Bit 6	62/61	DIF_14_En	Output Control overrides OE# pin	RW			1
Bit 5	60/59	DIF_13_En	Output Control overrides OE# pin	RW			1
Bit 4	56/55	56/55 DIF_12_En Output Control overrides OE# pin RW Hi-Z Ena		Enable	1		
Bit 3	53/52	DIF_11_En	Output Control overrides OE# pin	RW	111-2	Lilable	1
Bit 2	50/49	DIF_10_En	Output Control overrides OE# pin	RW			1
Bit 1	47/46	47/46 DIF_9_En Output Control overrides OE# pin RW			1		
Bit 0	42/41	DIF_8_En	Output Control overrides OE# pin	RW			1

SMBusTable: Output Enable Pin Status Readback Register

Byte	93 Pin#	Name	Control Function	Function Type		1	Default
Bit 7	57	OE_RB12	Real Time readback of OE#12	R			Real time
Bit 6	54	OE_RB11	Real Time readback of OE#11	R			Real time
Bit 5	51	OE_RB10	Real Time readback of OE#10	R			Real time
Bit 4	48	OE_RB9	Real Time readback of OE#9	R	OE# pin Low	OE# Pin High	Real time
Bit 3	43	OE_RB8	Real Time readback of OE#8	R	OE# pill Low		Real time
Bit 2	40	OE_RB7	Real Time readback of OE#7	R			Real time
Bit 1	37	OE_RB6	Real Time readback of OE#6	R			Real time
Bit 0	34	OE_RB5	Real Time readback of OE#5	R			Real time

SMBusTable: Reserved Register

Byte	e 4	Pin #	Name	Control Function	Type	0	1	Default		
Bit 7		Reserved								
Bit 6				Reserved				0		
Bit 5				Reserved						
Bit 4				Reserved				0		
Bit 3				Reserved						
Bit 2			Reserved							
Bit 1			Reserved							
Bit 0			Reserved							



SMBusTable: Vendor & Revision ID Register

Byte 5 Pin #		Name	Control Function	Type	0	1	Default
Bit 7	-	RID3		R			Х
Bit 6	-	RID2	REVISION ID	R	B rev	= 0001	X
Bit 5	-	RID1	REVISION ID	R	C Rev	= 0010	Х
Bit 4	-	RID0		R			Х
Bit 3	-	VID3		R	-	-	0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID1	VENDOR ID	R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBusTable: DEVICE ID

Byte 6 Pin #		Pin # Name Control Function		Туре	0	1	Default
Bit 7	-	De	evice ID 7 (MSB)	R			1
Bit 6	-		Device ID 6	R	7		1
Bit 5	-		Device ID 5		1		0
Bit 4	-		Device ID 4		Device ID is 219 decimal or		1
Bit 3	-		Device ID 3	R	DB	hex.	1
Bit 2	-		Device ID 2				0
Bit 1	-	Device ID 1		R			1
Bit 0	-		Device ID 0	R			1

SMBusTable: Byte Count Register

Byte 7 Pin #		Name	Control Function	Type	0	1	Default	
Bit 7			Reserved	. , , , ,		·	0	
Bit 6			Reserved					
Bit 5		Reserved						
Bit 4	-	BC4		RW			0	
Bit 3	-	BC3	Writing to this register configures how	RW	Default value	is 8 hex, so 9	1	
Bit 2	-	BC2	many bytes will be read back.	RW	bytes (0 to 8) w	ill be read back	0	
Bit 1	-	BC1	many bytes will be read back.	RW	by de	efault.	0	
Bit 0	-	BC0		RW			0	

SMBusTable: Reserved Register

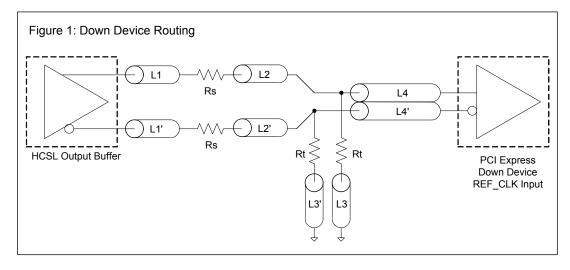
OMBUSTUBIC: Tieserveu Tiegistei									
Byte 8 Pin #		Name	Control Function	Type	0	1	Default		
Bit 7			Reserved						
Bit 6			Reserved				0		
Bit 5			Reserved						
Bit 4			Reserved				0		
Bit 3			Reserved				0		
Bit 2		Reserved							
Bit 1		Reserved							
Bit 0		Reserved							

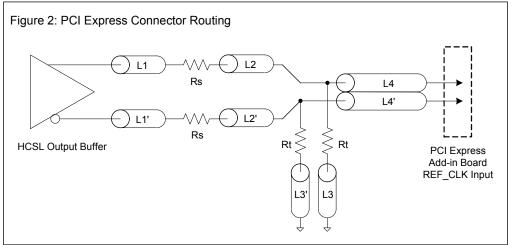


DIF Reference Clock						
Common Recommendations for Differential Routing	Dimension or Value	Unit	Figure			
L1 length, route as non-coupled 50ohm trace	0.5 max	inch	1			
L2 length, route as non-coupled 50ohm trace	0.2 max	inch	1			
L3 length, route as non-coupled 50ohm trace	0.2 max	inch	1			
Rs	33	ohm	1			
Rt	49.9	ohm	1			

Down Device Differential Routing		
L4 length, route as coupled microstrip 100ohm differential trace 2 min to 16	nax inch 1	
L4 length, route as coupled stripline 100ohm differential trace 1.8 min to 1	.4 max inch 1	

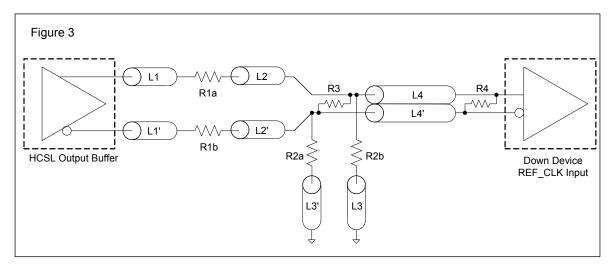
Differential Routing to PCI Express Connector			
L4 length, route as coupled microstrip 100ohm differential trace	0.25 to 14 max	inch	2
L4 length, route as coupled stripline 100ohm differential trace	0.225 min to 12.6 max	inch	2



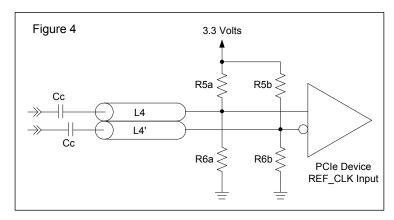


	Alternative Termination for LVDS and other Common Differential Signals (figure 3)						
Vdiff	Vp-p	Vcm	R1	R2	R3	R4	Note
0.45v	0.22v	1.08	33	150	100	100	
0.58	0.28	0.6	33	78.7	137	100	
0.80	0.40	0.6	33	78.7	none	100	ICS874003i-02 input compatible
0.60	0.3	1.2	33	174	140	100	Standard LVDS

R1a = R1b = R1R2a = R2b = R2

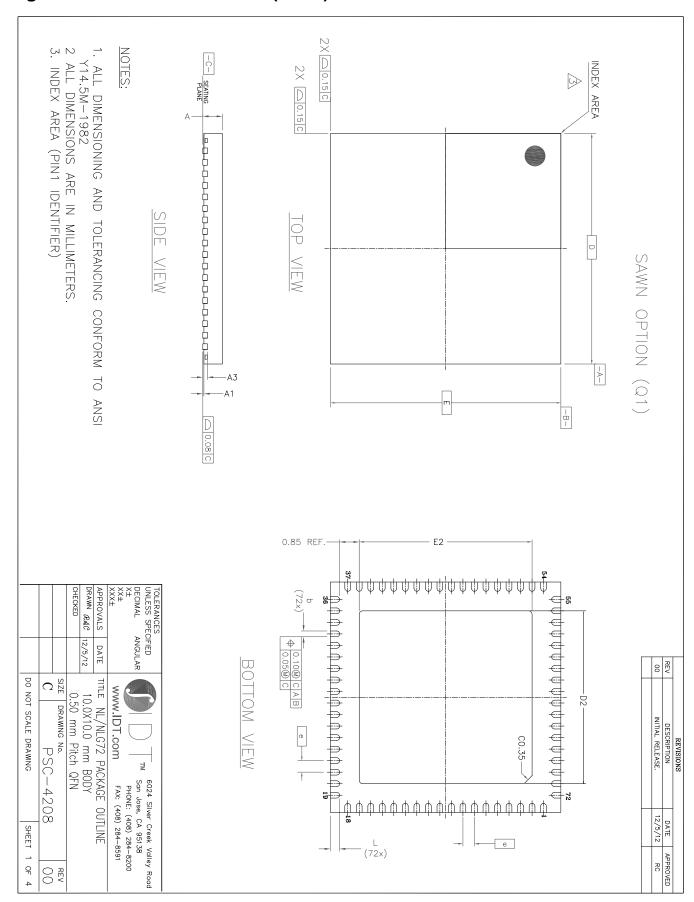


Cable Connected AC Coupled Application (figure 4)					
Component	Value	Note			
R5a, R5b	8.2K 5%				
R6a, R6b	1K 5%				
Cc	0.1 μF				
Vcm	0.350 volts				



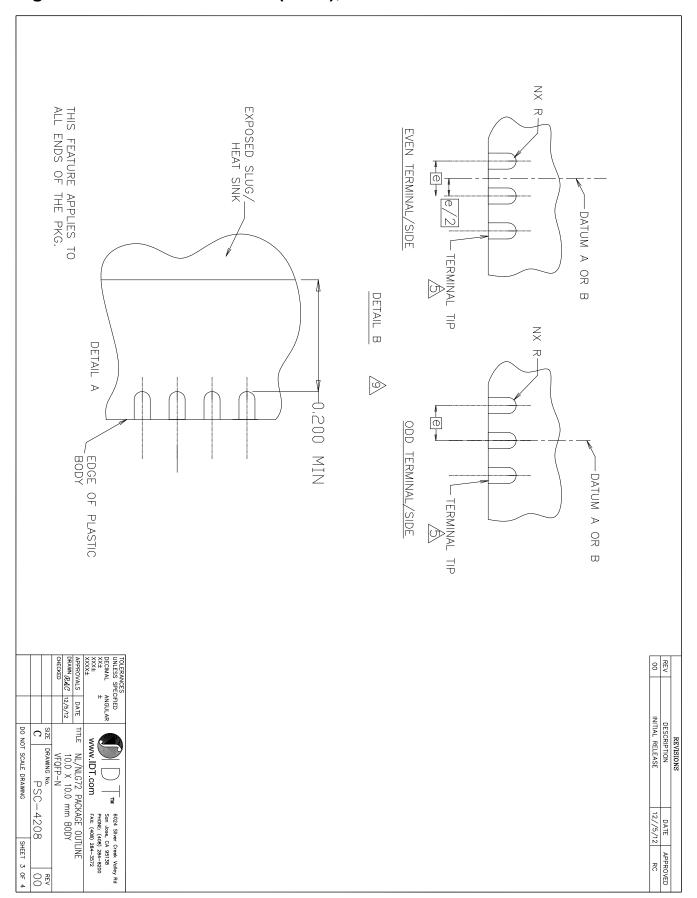


# Package Outline and Dimensions (NL72)





# Package Outline and Dimensions (NL72), cont.





# Package Outline and Dimensions (NL72) cont. – use EPAD Option P3 and Lead Option Z2

THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JEDEC PUB. 95 SEC. 4.3 SPP-002. DETAILS OF TERMINA IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.  DIMENSION 6 APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25mm AND 0.30mm FROM TERMINAL TIP.  ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.  T. DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.	SYMBOL 0.40mm 0.50mm  SYMBOL 0.10 0.15  dad 0.10 0.10  ccc 0.10 0.10  ddd 0.05 0.05  NOTES:  1. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994. 2. ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES. 3. N IS THE TOTAL NUMBER OF TERMINALS. Nd IS THE NUMBER OF TERMINALS IN X-DIRECTION & Ne IS THE NUMBER OF TERMINALS IN Y-DIRECTION.	SAW VERSION:  S DIMENSION  MIN. NOM. MAX.  D2 SEE EPAD OPTION  E2 SEE EPAD OPTION  K 0.20 6  Nd 18 6  Ne 18 6  TOLERANCE OF FORM & POSITION  TOLERANCE OF FORM & POSITION
NUMBERING CONVENTION  3 SPP-002. DETAILS OF TERMINAL #1 CATED WITHIN THE ZONE  Y BE EITHER A MOLD  INAL AND IS MEASURED BETWEEN  RMINALS ON EACH D AND E  CAL FASHION.	ASME Y14.5M-1994.  ES ARE IN DEGREES.  RECTION & RECTION.	EPAD OPTION:  P1  MIN. NOM.  E2 7.40 7.50  D2 7.40 7.50  LEAD OPTION  MIN. NOM.  O.45 0.50
AND DO COMPANY OF THE PROPERTY	COMMON SYMBOL A A O.S A1 O.S A1 O.S A1 O.S B1 R1 R1 R ref R ref. b min NOTES b O.S	MAX. MIN. 5.90 5.90 MAX. MIN. 0.55 0.30
DIMENSION  NOM. MAX.  REPAD OPTION  9.75 BSC  9.75 BSC  18  18  6  0.65  1.00	ON DIMENSIONS  MIN NOM MAX  0.80 0.90 1.00  0.02 0.05  - 0.20 ref - 14  - 0.20 - 14  - 0.20 - 14  - 0.20 - 0.30  min/2 1,2  0.18 0.25 0.30  0.50 BSC  10.00 BSC	P2 NOM. MAX. 6.00 6.10 6.00 6.10 NOM. MAX. 0.40 050
TOLERANCES UNLESS SPECIFED DECINAL ANGULAR XXX± XXX± XXXX± XXXXX APPROVALS DATE TITLE N DRAWN (BACC 12/5/72 V CHECKED C DR.  SZE DR. 1 DO NOT SI		REVISIONS   REVISIONS   REV   DESCRIPTION   OO   INITIAL RELEASE   P 3   MIN.   NOM.   5.80   5.90   5.80   5.90   5.90
WWW.IDT.com  The NL/NIG72 PACKAGE OUTLINE 10.0 X 10.0 mm BODY VFQFP-N  SZE PRAWNG No. PSC-4208  DO NOT SCALE DRAWNG  SHORT Creek Valley Rd Son John, CA 95138 PHONE (106) 284-2572 PACKAGE OUTLINE 10.0 X 10.0 mm BODY VFQFP-N  SZE PSC-4208  SHEET 4 0F 4		NONS    DATE   APPROVED



# **Marking Diagram**



#### Notes:

- 1. "LOT" is the lot sequence number.
- 2. "COO" denotes country of origin.
- 3. "YYWW" is the last two digits of the year and week that the part was assembled.
- 4. "LF" denotes RoHS compliant package.

# **Ordering Information**

Part / Order Number	t / Order Number   Shipping Package   F		Temperature
9ZX21901CKLF	Trays	72-pin VFQFPN	0 to +70°C
9ZX21901CKLFT	Tape and Reel	72-pin VFQFPN	0 to +70°C

# **Revision History**

Rev.	Issue Date	Who	Description	Page #
K 4	4/15/2013	IKIJVVI	1. Corrected typo in OE# Latency parameter; changed 1 min. to 3 max. cycles to 4	5
N.	K 4/15/2013		min. to 12 max. clocks.	
L	1/30/2015	DC	Updated package dimensions and outline drawing with NL72 SAWN version.	Various
M 4/23/2015	4/00/0015		Added marking diagram and associated notes.	Various
		2. Re-created datasheet in latesrt IDT template.	various	
N	11/19/2015	1/19/2015 RDW	Update Input Clock spec with new standardized table matching PCIe SIG input	5
			specs.	



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